## NSN 5962-01-136-2977

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View Online at https://aerobasegroup.com/nsn/5962-01-136-2977

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inch	es and 0.310 inches
Body Height:	
Between 0.140 inch	es and 0.185 inches
Maximum Power D	ssipation Rating:
794.0 milliwatts	
Operating Tempur	iture Range:
-55.0/+125.0 degree	s celsius
Storage Tempurate	ire Range:
-65.0/+150.0 degree	s celsius
End Application:	
B-52g/h wst 36378	
Features Provided	
Hermetically sealed	and monolithic and bipolar and schottky and high impedance and 3-state output and programmable
Inclosure Material:	
Ceramic and glass	
Inclosure Configur	ation:
Dual-in-line	
Output Logic Form	:
Transistor-transistor	logic
Input Circuit Patte	n:
10 input	
Case Outline Sour	e And Designator:
D-2 mil-m-38510	
Terminal Surface 1	reatment:
Solder	
Voltage Rating And	I Type Per Characteristic:
-0.5 volts power so	Irce and 7.0 volts power source
Time Rating Per C	acteristic:
40.00 nanoseconds	propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Ty	be:
Prom	
Memory Capacity:	
Unknown	
Terminal Type And	Quantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

